



CHENMKO ENTERPRISE CO.,LTD

Lead free devices

SURFACE MOUNT
SCHOTTKY BARRIER DIODE
VOLTAGE 40 Volts CURRENT 0.04 Ampere

CH720S-40PT

APPLICATION

- * Low barrier diode for detectors up to GHz frequencies

FEATURE

- * Small surface mounting type. (SC-79/SOD-523)
- * Low VF and low IR
- * High reliability

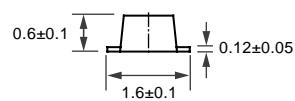
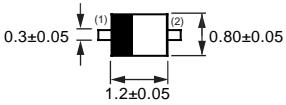
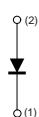
CONSTRUCTION

- * Silicon epitaxial planar

MARKING

- * F

CIRCUIT



Dimensions in millimeters

SC-79/SOD-523

MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

| RATINGS | SYMBOL | CH720S-40PT | | | UNITS |
|--|---------------------|-------------|------|------|-------|
| | | MIN. | TYP. | MAX. | |
| Maximum Recurrent Peak Reverse Voltage | V _{RRM} | - | - | 40 | Volts |
| Maximum Average Forward Rectified Current | I _o | - | - | 40 | mAmps |
| Total Power Dissipation, Ts< 85 °C | P _{TOT} | - | - | 150 | mW |
| Typical Series Inductance | L _S | - | 0.6 | - | nH |
| Typical Case Capacitance | C _c | - | 0.09 | - | pF |
| Typical Junction Capacitance between Terminal (Note 1) | C _J | - | 0.35 | 0.6 | pF |
| Typical Differential Resistance (Note 2) | R _o | - | 225 | - | kΩ |
| Operating and Storage Temperature Range | T _{J,TSTG} | -55 | - | +150 | °C |

ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

| CHARACTERISTICS | SYMBOL | CH720S-40PT | | | UNITS |
|---|----------------|-------------|------|------|-------|
| | | MIN. | TYP. | MAX. | |
| Maximum Instantaneous Forward Voltage at I _F = 2mA | V _F | - | 0.58 | 1.00 | Volts |
| Maximum Average Reverse Current at V _R = 40V | I _R | - | - | 10 | uAmps |

NOTES : 1. Measured at 1.0 MHz and applied reverse voltage of 0 volts.

2. Measured at 1.0 kHz and applied reverse voltage of 0 volts.

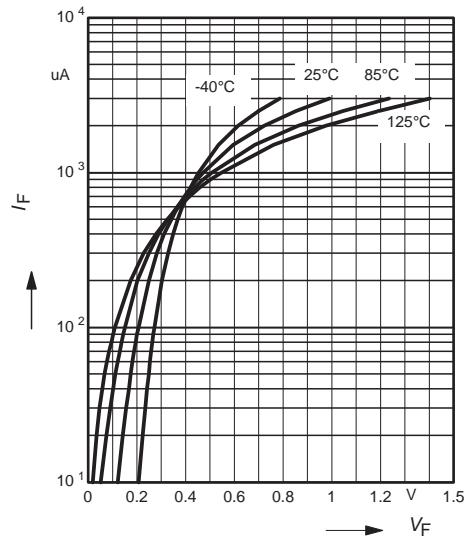
2. ESD sensitive product handling required.

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RATING CHARACTERISTIC CURVES (CH720S-40PT)

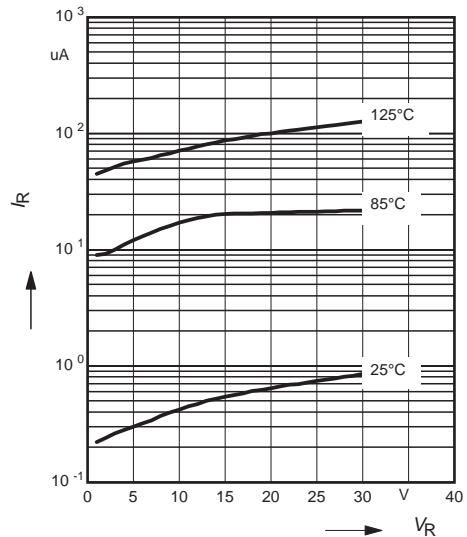
Forward current $I_F = f(V_F)$

T_A = parameter



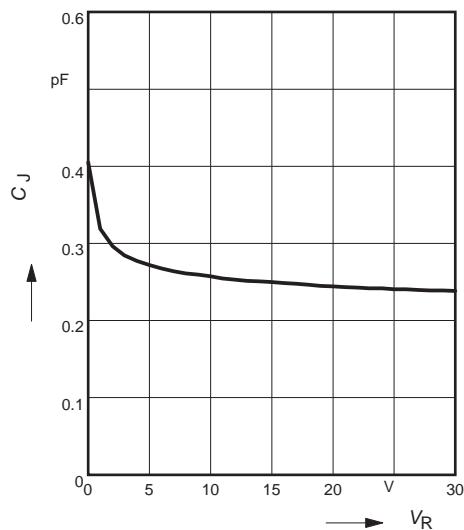
Leakage current $I_R = f(V_R)$

T_A = Parameter



Diode capacitance $C_J = f(V_R)$

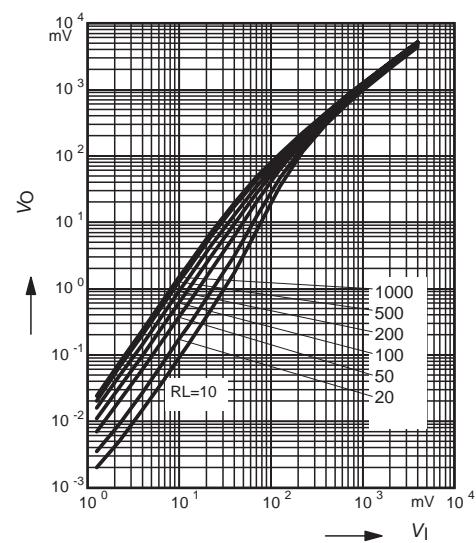
$f = 1\text{MHz}$



Rectifier voltage $V_{\text{out}} = f(V_{\text{in}})$

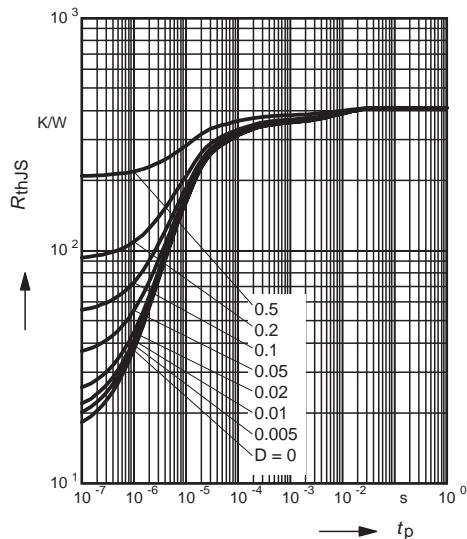
$f = 900\text{ MHz}$

R_L = parameter in $\text{k}\Omega$



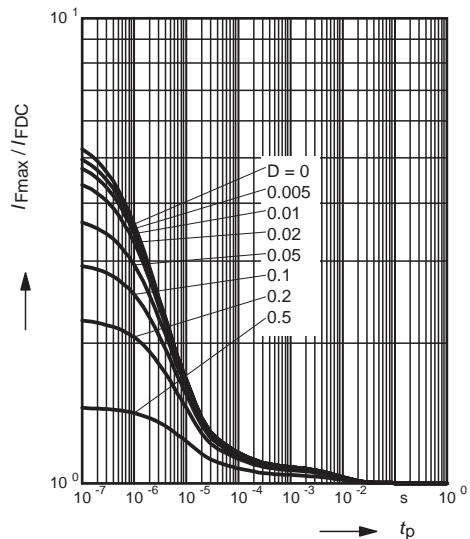
RATING CHARACTERISTIC CURVES (CH720S-40PT)

Permissible Pulse Load $R_{\text{thJS}} = f(t_p)$



Permissible Pulse Load

$$I_{F\max} / I_{FDC} = f(t_p)$$



Forward current $I_F = f(T_S)$

